

### ISL22511

Single Push Button Controlled Potentiometer (XDCP™) Low Noise, Low Power, 32 Taps, Push Button Controlled Potentiometer

The <u>ISL22511</u> is a three-terminal digitally-controlled potentiometer (XDCP) implemented by a resistor array composed of 31 resistive elements and a wiper switching network. The ISL22511 features a push button control, a Shutdown mode, and an industry-leading UTQFN package.

The push button control has individual  $\overline{PU}$  and  $\overline{PD}$  inputs for adjusting the wiper. To eliminate redundancy, the wiper position automatically increments or decrements if one of these inputs is held longer than one second.

Forcing both  $\overline{PU}$  and  $\overline{PD}$  low for more than two seconds activates shutdown mode. Shutdown mode disconnects the top of the resistor chain and moves the wiper to the lowest position to minimize power consumption.

The three terminals accessing the resistor chain naturally configure the ISL22511 as a voltage divider. A rheostat is easily formed by floating an end terminal or connecting it to the wiper.

#### **Related Literature**

For a full list of related documents, visit our website:

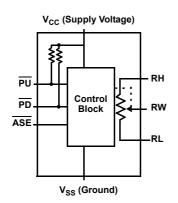
• ISL22511 device page

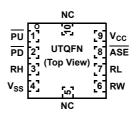
#### **Applications**

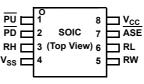
- · Volume control
- · LED/LCD brightness control
- · Contrast control
- · Programming bias voltages
- · Ladder networks

#### **Features**

- · Solid-state non-volatile potentiometer
- · Push button controlled
- · Single or auto increment/decrement
  - o Fast mode after 1s button press
- AUTOSTORE of last wiper position or manual store of wiper position
- · Shutdown mode
- 32 wiper tap points
  - Max scale wiper position on power-up
- · Low power CMOS
  - $\circ V_{CC} = 2.7V \text{ to } 5.5V$
  - $\circ$  Terminal voltage, 0V to  $V_{CC}$
  - o Standby current, 3µA max
- $R_{TOTAL}$  value =  $10k\Omega$
- · High reliability
  - Endurance: 1000000 data changes per bit per register
  - Register data retention: 50 years at T ≤ +55°C
- Packages
  - o 8 Ld SOIC
  - 10 Ld UTQFN (2.1mmx1.6mm)
- · Pb-free (RoHS compliant)







ISL22511 1. Overview

#### 1. Overview

#### 1.1 **Block Diagrams**

General Detailed V<sub>CC</sub> (Supply Voltage) 5-Bit 31 RH PU Up/Down Counter 30 29 RH PU 5-Bit 28 Nonvolatile One Control Memory PD of and Memory RW RW 32 Transfer Gates Resistor Decoders Array ASE Store and Control RL ASE 2 Circuitry V<sub>SS</sub> (Ground) RL

Figure 1. Block Diagrams

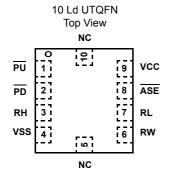
#### 1.2 **Ordering Information**

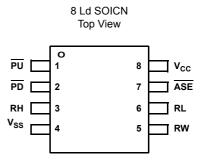
Part Number ( <u>Note 4</u> )	Part Marking	R <sub>TOTAL</sub> (kΩ)	Temp. Range (°C)	Tape and Reel (Units) (Note 1)	Package (RoHS Compliant)	Pkg. Dwg. #
ISL22511WFRU10Z-TK ( <u>Note 3</u> )	GD	10	-40 to +125	1k	10 Ld UTQFN	L10.2.1x1.6A
ISL22511WFB8Z (No longer available or supported) (Note 2)	22511 WFBZ	10	-40 to +125	-	8 Ld SOIC	M8.15

#### Notes:

- 1. See TB347 for details about reel specifications.
- 2. These Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J-STD-020.
- 3. These Pb-free plastic packaged products employ special Pb-free material sets; molding compounds/die attach materials and NiPdAu-Ag plate - e4 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J-STD-020.
- 4. For Moisture Sensitivity Level (MSL), see the ISL22511 device page. For more information about MSL, see TB363.

#### 1.3 **Pin Configurations**





ISL22511 1. Overview

# 1.4 Pin Descriptions

UTQFN Pin	SOIC Pin	Symbol	Description
1	1	PU	Falling-edge triggered input with internal pull-up. Toggle $\overline{PU}$ to move the wiper close to the RH terminal. The debounced PU input increments the wiper position. An on-chip pull-up holds the $\overline{PU}$ input HIGH. A switch closure to ground or a LOW logic level moves the wiper to the next adjacent higher tap position after a debounce time.
2	2	PD	Falling-edge triggered input with internal pull-up. Toggle $\overline{PD}$ to move the wiper close to the RL terminal. The debounced $\overline{PD}$ input decrements the wiper position. An on-chip pull-up holds the $\overline{PD}$ input HIGH. A switch closure to ground or a LOW logic level moves the wiper to the next adjacent lower tap position after a debounce time.
3	3	RH	The RH and RL pins are equivalent to the fixed terminals of a mechanical potentiometer. The minimum voltage is V <sub>SS</sub> and the maximum voltage is V <sub>CC</sub> . The terms RH and RL refer to the relative position of the terminal in relation to the wiper movement direction selected by the PU/PD input.
4	4	VSS	Ground
5, 10	-	NC	No connection
6	5	RW	Wiper terminal of the potentiometer, which is equivalent to the movable terminal of a mechanical potentiometer.
7	6	RL	The RH and RL pins are equivalent to the fixed terminals of a mechanical potentiometer. The minimum voltage is V <sub>SS</sub> and the maximum voltage is V <sub>CC</sub> . The terms RH and RL refer to the relative position of the terminal in relation to the wiper movement direction selected by the PU/PD input.
8	7	ASE	Active low AUTOSTORE enable input or Manual Store active low input. The debounced ASE pin can be in one of two states:     AUTOSTORE is enabled if ASE is held LOW during power up.     AUTOSTORE is disabled if ASE is held HIGH during power-up. A LOW to HIGH transition initiates a manual store operation to enable connection of a push button switch to this pin. For every valid push, the ISL22511 stores the current wiper position to the EEPROM.
9	8	VCC	Supply voltage

ISL22511 2. Specifications

## 2. Specifications

## 2.1 Absolute Maximum Ratings

Parameter	Minimum	Maximum	Unit		
Storage Temperature	-65	+150	°C		
Voltage at PU and PD pin with respect to GND	-0.3	V <sub>CC</sub> + 0.3	V		
V <sub>CC</sub>	-0.3	+6	V		
Voltage at any DCP pin with respect to GND	-0.3	V <sub>CC</sub>	V		
I <sub>W</sub> (10s)		±6	mA		
ESD Rating	Va	Value			
Human Body Model (Tested per JS-001-2017)	er JS-001-2017) 4				
Machine Model	300				
Latch-Up (Tested per JESD78E; Class 2, Level A)	10	100			

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions can adversely impact product reliability and result in failures not covered by warranty.

### 2.2 Thermal Information

Thermal Resistance (Typical)	θ <sub>JA</sub> (°C/W)	θ <sub>JC</sub> (°C/W)
10 Lead UTQFN Package (Notes 5, 6)	150	48.3
8 Lead SOIC Package (Note 5)	125	N/A

#### Notes

<sup>6.</sup>  $\theta_{JC}$  is for the location in the center of the exposed metal pad on the package underside.

Parameter	Minimum	Maximum	Unit	
Maximum Junction Temperature (Plastic Package)		+150	°C	
Pb-Free Reflow Profile	see <u>TB493</u>			

## 2.3 Recommended Operation Conditions

Parameter	Minimum	Maximum	Unit
Temperature Range (Extended Industrial)	-40	+125	°C
V <sub>CC</sub>	2.7	5.5	V
Power Rating		15	mW
Wiper Current		±3.0	mA

## 2.4 Electrical Specifications

## 2.4.1 Potentiometer Specifications

Over recommended operating conditions, unless otherwise specified.

Parameter	Symbol	Test Conditions	Min (Note 20)	Typ ( <u>Note 7</u> )	Max ( <u>Note 20</u> )	Unit
RH to RL Resistance	R <sub>TOTAL</sub>			10		kΩ
RH to RL Resistance Tolerance			-20		+20	%
End-to-End Temperature Coefficient				±80		ppm/°C (Note 18)

θ<sub>JA</sub> is measured in free air with the component mounted on a high-effective thermal conductivity test board with "direct attach" features.
 See <u>TB379</u>.

ISL22511 2. Specifications

Over recommended operating conditions, unless otherwise specified. (Continued)

Parameter	Symbol	Test Conditions	Min (Note 20)	Typ ( <u>Note 7</u> )	Max (Note 20)	Unit
Wiper Resistance	R <sub>W</sub>	V <sub>CC</sub> = 3.3V, wiper current I <sub>RW</sub> = V <sub>CC</sub> /R <sub>TOTAL</sub>		130	400	W
V <sub>RH</sub> and V <sub>RL</sub> Terminal Voltages	$V_{RH}, V_{RL}$	V <sub>RH</sub> and V <sub>RL</sub> to GND	0		V <sub>CC</sub>	V
Noise on Wiper Terminal		From 0Hz to 10MHz		-80		dBV
Potentiometer Capacitance (Note 19)	C <sub>H</sub> /C <sub>L</sub> /C <sub>W</sub>			10/10/25		pF
Leakage on DCP Pins	I <sub>LkgDCP</sub>	Voltage at pin from GND to V <sub>CC</sub>		0.05	0.4	μA
Voltage Divider Mode (0V at R <sub>L</sub> ; V	CC at RH; me	easured at RW unloaded)	•			
Integral Non-Linearity	INL ( <u>Note 12</u> )		-1		1	LSB ( <u>Note 8</u> )
Differential Non-Linearity	DNL ( <u>Note 11</u> )	Monotonic over all tap positions	-0.5		0.5	LSB ( <u>Note 8</u> )
Zero-Scale Error	ZSerror (Note 9)		0	0.1	2	LSB ( <u>Note 8</u> )
Full-Scale Error	FSerror (Note 10)		-2	-0.1	0	LSB ( <u>Note 8</u> )
Ratiometric Temperature Coefficient	TC <sub>V</sub> (Note 13)	Wiper from 5 hex to 1F hex		±25		ppm/°C
3dB Cutoff Frequency	f <sub>CUTOFF</sub>	Wiper at the middle scale		500		kHz
Resistor Mode (Measurements b	etween RW ar	nd RL with RH not connected, or betwee	n RW and R	H with RL	not connect	ed)
Integral Non-Linearity	RINL (Note 17)	DCP register set between 1 hex and 1F hex; monotonic over all tap positions	-1.5		1.5	MI ( <u>Note 14</u> )
Differential Non-Linearity	RDNL (Note 16)		-0.5		0.5	MI ( <u>Note 14</u> )
Offset	Roffset (Note 15)	W option	0	1	2	MI ( <u>Note 14</u> )

## 2.4.2 DC Electrical Specifications

Over recommended operating conditions unless otherwise specified.

Parameter	Symbol	Test Conditions	Min ( <u>Note 20</u> )	Typ ( <u>Note 7</u> )	Max (Note 20)	Unit
V <sub>CC</sub> Active Current	Icc	V <sub>CC</sub> = 5.5V, perform wiper move operation			150	μΑ
V <sub>CC</sub> Current During Store Operation	I <sub>CC</sub>	V <sub>CC</sub> = 5.5V, perform non-volatile store operation			2	mA
Standby Current	I <sub>SB</sub>			0.6	3	μA
PU, PD Input Leakage Current	I <sub>Lkg</sub>	$V_{IN} = V_{SS}$ to $V_{CC}$	-2		+2	μA
PU, PD Input HIGH Voltage	V <sub>IH</sub>		V <sub>CC</sub> x 0.7			V
PU, PD input LOW Voltage	V <sub>IL</sub>				V <sub>CC</sub> x 0.1	V
PU, PD Input Capacitance (Note 19)	C <sub>IN</sub>	V <sub>CC</sub> = 3.3V, T <sub>A</sub> = +25°C, f = 1MHz		10		pF
Pull-Up Resistor for PU and PD (Note 19)	Rpull_up			1		МΩ
EEPROM Specifications	1					
EEPROM Endurance			1000000			Cycles
EEPROM Retention		Temperature ≤ +55°C	50			Years

ISL22511 2. Specifications

## 2.4.3 AC Electrical Specifications

Over recommended operating conditions unless otherwise specified.

Parameter	Symbol	Min ( <u>Note 20</u> )	Typ ( <u>Note 7</u> )	Max ( <u>Note 20</u> )	Unit
Time Between Two Separate Push Button Events	t <sub>GAP</sub>	2			ms
Debounce Time	t <sub>DB</sub>		15	28	ms
Wiper Change on a Slow Mode	t <sub>S SLOW</sub>	100	250	390	ms
Wiper Change on a Fast Mode	t <sub>S FAST</sub>	25	50	78	ms
Time to Enter Shutdown Mode (keep PU and PD LOW) (Note 19)	t <sub>stdn</sub>		2		S
Power-Up to Wiper Stable	t <sub>PU</sub>			500	μs
V <sub>CC</sub> Power-Up Rate	t <sub>R</sub> VCC	0.2		50	V/ms

#### Notes:

- 7. Typical values are for  $T_A = +25^{\circ}C$  and 3.3V supply voltage.
- 8. LSB: [V(RW)<sub>31</sub> V(RW)<sub>0</sub>]/31. V(RW)<sub>31</sub> and V(RW)<sub>0</sub> are the voltage on the RW pin for the DCP register set to 1F hex and 00 hex, respectively. LSB is the incremental voltage when changing from one tap to an adjacent tap.
- 9. ZS error =  $V(RW)_0/LSB$ .
- 10. FS error =  $[V(RW)_{31} V_{CC}]/LSB$ .
- 11. DNL =  $[V(RW)_i V(RW)_{i-1}]/LSB$  -1, for i = 1 to 31; i is the DCP register setting.
- 12.  $INL = [V(RW)_i i \cdot LSB V(RW)]/LSB$  for i = 1 to 31
- 13. See Equation 1.

(EQ. 1) 
$$TC_{V} = \frac{Max(V(RW)_{j}) - Min(V(RW)_{j})}{[Max(V(RW)_{j}) + Min(V(RW)_{j})]/2} \times \frac{10^{6}}{+165^{\circ}C}$$

for i = 5 to 31 decimal,  $T = -40^{\circ}C$  to  $+125^{\circ}C$ . Max ( ) is the maximum value of the wiper voltage and Min ( ) is the minimum value of the wiper voltage over the temperature range.

- 14.  $MI = |RW_{31} RW_0|/31$ . MI is a minimum increment.  $RW_{31}$  and  $RW_0$  are the measured resistances for the DCP register set to 1F hex and 00 hex, respectively.
- Roffset = RW<sub>0</sub>/MI when measuring between RW and RL.
   Roffset = RW<sub>31</sub>/MI when measuring between RW and RH.
- 16. RDNL =  $(RW_i RW_{i-1})/MI$  for i = 1 to 31.
- 17. RINL =  $[RW_i (MI \cdot i) RW_0]/MI$  for i = 1 to 31.
- 18. See Equation 2.

(EQ. 2) 
$$TC_{R} = \frac{[Max(Ri) - Min(Ri)]}{[Max(Ri) + Min(Ri)]/2} \times \frac{10^{6}}{+165^{\circ}C}$$

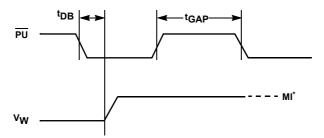
for i = 5 to 31 decimal,  $T = -40^{\circ}C$  to  $+125^{\circ}C$ . Max ( ) is the maximum value of the wiper voltage and Min ( ) is the minimum value of the resistance over the temperature range.

- 19. Limits should be considered typical and are not production tested.
- 20. Parameters with Min and/or Max limits are 100% tested at +25°C, unless otherwise specified. Temperature limits established by characterization and are not production tested.

ISL22511 3. Timing Diagrams

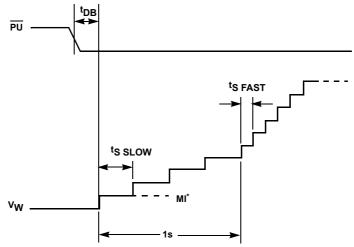
# 3. Timing Diagrams

## 3.1 Slow Mode Timing



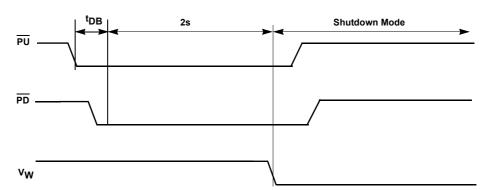
\*MI is the minimum incremental change in the wiper voltage.

## 3.2 Fast Mode Timing



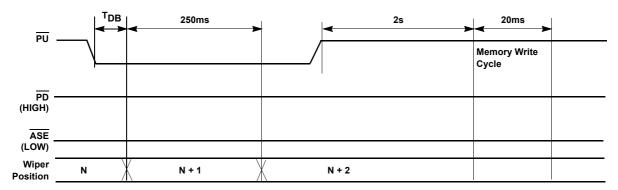
<sup>\*</sup> MI is the minimum incremental change in the wiper voltage.

## 3.3 Shutdown Mode Timing



ISL22511 3. Timing Diagrams

## 3.4 AUTOSTORE Mode Timing



# 4. Typical Performance Curves

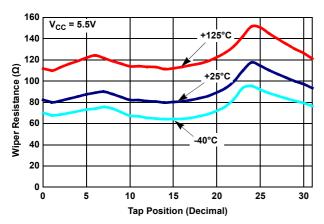


Figure 2. Wiper Resistance vs Tap Position [  $I(RW) = V_{CC}/R_{TOTAL}$  ] for  $10k\Omega$ 

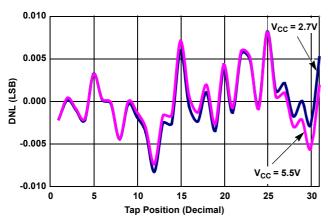


Figure 4. DNL vs Tap Position in Voltage Divider Mode for  $10k\Omega$  (W)

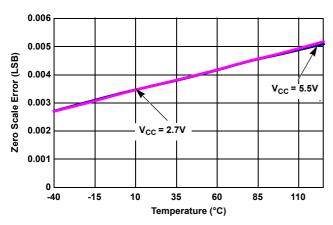


Figure 6. ZS Error vs Temperature

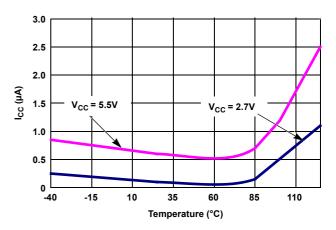


Figure 3. Standby  $I_{\text{CC}}$  vs Temperature

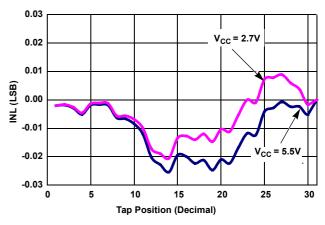


Figure 5. INL vs Tap Position in Voltage Divider Mode for  $10k\Omega$  (W)

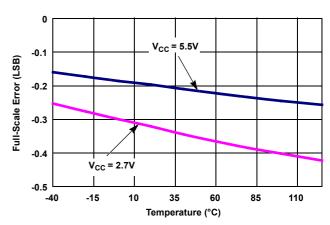


Figure 7. FS Error vs Temperature

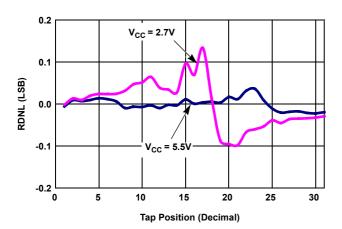


Figure 8. DNL vs Tap Position in Rheostat Mode for  $10k\Omega$  (Wiper)

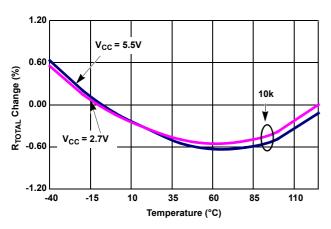


Figure 10. End to End  $R_{TOTAL}$  % Change vs Temperature

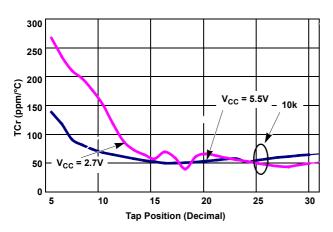


Figure 12. TC for Rheostat Mode in ppm

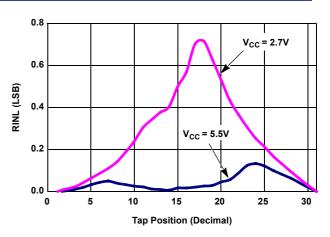


Figure 9. INL vs Tap Position in Rheostat Mode for  $10k\Omega$  (Wiper)

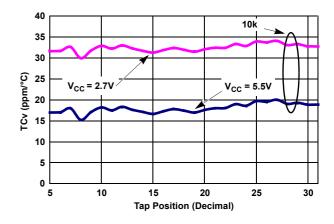


Figure 11. TC for Voltage Divider Mode

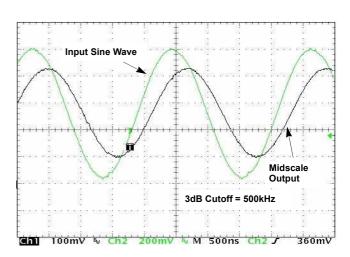
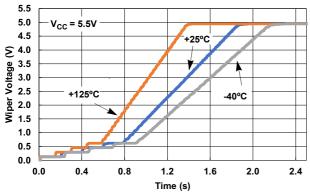
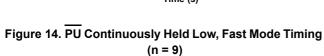


Figure 13. Frequency Response (500kHz)





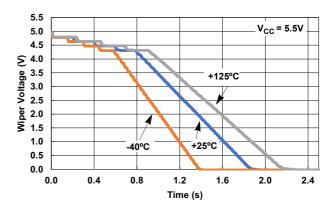


Figure 15. PD Continuously Held Low, Fast Mode Timing (n = 9)

ISL22511 5. Device Overview

### 5. Device Overview

## 5.1 Power-Up and Power-Down Requirements

There are no restrictions on the power-up or power-down conditions of  $V_{CC}$  and the voltages applied to the potentiometer pins if  $V_{CC}$  is always more positive than or equal to  $V_{RH}$  and  $V_{RL}$ ,  $(V_{CC} \ge V_{RH}, V_{RL})$ . The  $V_{CC}$  ramp rate specification is always in effect.

### 5.2 Operating the Device

The ISL22511 consists of three sections:

- · Input control, counter, and decode section
- · EEPROM memory
- · Resistor array

The input control section operates just like an up/down counter. The output of this counter is decoded to turn on a single electronic switch and connects a point on the resistor array to the wiper output. Under the proper conditions, the contents of the counter can be stored in EEPROM memory and retained for future use. The resistor array is comprised of 31 individual resistors connected in series. At either end of the array and between each resistor is an electronic switch that transfers the potential at that point to the wiper.

Note: The ISL22511 is programmed from the factory with the wiper set to the highest position: 0x1Fh.

The ISL22511 interfaces directly to two push button switches to effectively move the wiper up or down. The  $\overline{PU}$  input increments a 5-bit counter and the  $\overline{PD}$  input decrements a 5-bit counter. The output of this counter is decoded to select one of the 32 wiper positions along the resistive array. The wiper increment input ( $\overline{PU}$ ) and the wiper decrement input ( $\overline{PD}$ ) are both connected to an internal pull-up so that they normally remain HIGH. When pulled LOW by an external push button switch or a logic LOW level input, the wiper is switched to the next adjacent tap position.

Internal debounce circuitry prevents inadvertent switching of the wiper position if  $\overline{PU}$  or  $\overline{PD}$  remain LOW for less than 15ms, typical. Each of the buttons can be pushed either once for a single increment/decrement or continuously for multiple increments/decrements. The number of increments/decrements of the wiper position depends on how long the button is pushed. When making a continuous push, the increment/decrement speed increases after the first second. The device is in Slow Scan mode for the first second. If the button is held for longer than one second, the device goes into Fast Scan mode. The ISL22511 returns to the standby condition as soon as the button is released.

If two or more buttons are pressed simultaneously, all commands are ignored upon release of ALL buttons, except the Shutdown mode condition.

When the wiper is at either fixed terminal, it acts like its mechanical equivalent and does not move beyond the last position. That is, the counter does not wrap around when clocked to either extreme.

### 5.3 AUTOSTORE

The counter value is stored in EEPROM memory after two seconds of no activity on the  $\overline{PU}$  or  $\overline{PD}$  inputs while  $\overline{ASE}$  is enabled (held LOW). When power is restored, the content of the memory is recalled and the counter resets to the last value stored.

If AUTOSTORE is implemented,  $\overline{ASE}$  is typically hard-wired to VSS. If  $\overline{ASE}$  is held HIGH during power-up and then taken LOW, the wiper does not respond to the  $\overline{PU}$  or  $\overline{PD}$  inputs until  $\overline{ASE}$  is brought HIGH and held HIGH.

ISL22511 5. Device Overview

## 5.4 Manual (Push Button) Store

When  $\overline{\mathsf{ASE}}$  is not enabled (held HIGH), a push button switch can be used to pull  $\overline{\mathsf{ASE}}$  LOW for more than 15ms and released to perform a manual store of the wiper position.

**Note:** If  $\overline{\mathsf{ASE}}$  is pulled LOW while either the  $\overline{\mathsf{PU}}$  or  $\overline{\mathsf{PD}}$  inputs are held LOW continuously, no store to the EEPROM occurs.

During memory write cycles, all inputs are ignored.

#### 5.5 Shutdown Mode

The ISL22511 enters Shutdown mode if both the  $\overline{PU}$  and  $\overline{PD}$  inputs are kept LOW for two seconds. In Shutdown mode, the resistors array is totally disconnected from its RH pin and the wiper is moved to the position closest to the RL pin, as shown in Figure 16.

**Note:** The  $\overline{PU}$  and  $\overline{PD}$  inputs must be pulled LOW within the  $t_{DB}$  time window of 15ms, otherwise, all commands are ignored until both inputs are released. See <u>"Shutdown Mode Timing" on page 7</u> for more information.

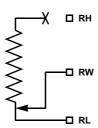


Figure 16. DCP Connection in Shutdown Mode

Holding either the  $\overline{PU}$ ,  $\overline{PD}$ , or ASE input LOW for more than 15ms causes the ISL22511 to exit Shutdown mode and return the wiper to the prior shutdown position. If  $\overline{PU}$  or  $\overline{PD}$  are held LOW for more than 250ms, the ISL22511 starts auto-incrementing or auto-decrementing the wiper position.

## 5.6 R<sub>TOTAL</sub> with V<sub>CC</sub> Removed

The end-to-end resistance of the array fluctuates when  $V_{CC}$  is removed.

ISL22511 6. Revision History

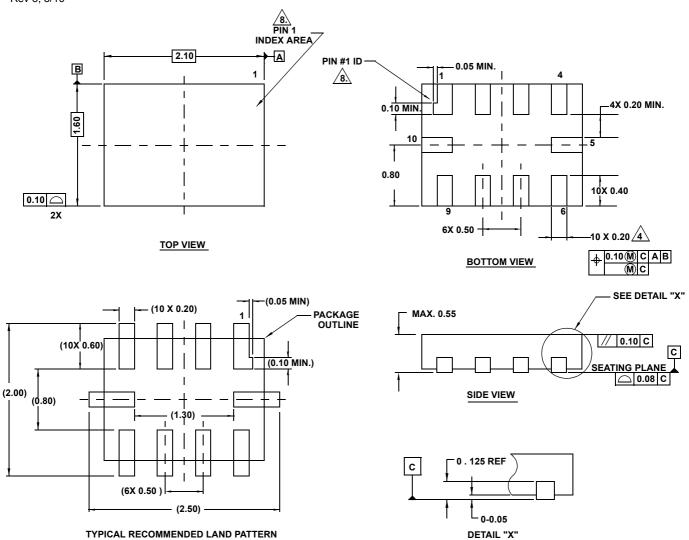
# 6. Revision History

Rev.	Date	Description
3.00	May.13.19	Applied new format.  Updated ordering Information table by removing all 50k parts, adding tape and reel column, and updated notes. Added Related Literature section on page 1.  Updated Figures 10, 11, and 12 removing the information for 50k parts.  Removed all references to U option on page 5  Added Figures 14 and 15 on page 11.  Under Features Section changed "Middle Scale Wiper Position on Power-up" with "Max Scale Wiper Position on Power-Up".  Under device overview in page 12 replace "Note the ISL22511 is programmed from the factory with the wiper set to RH tap" with "Note: The ISL22511 is programmed from the factory with the wiper set to the highest position 0x1Fh."
2.00	Sep.9.15	- Ordering Information Table on page 2 Added About Intersil section Updated POD L10.2.1X1.6A to latest revision changes are as follow:     Updated to new POD format by removing table listing dimensions and moving dimensions onto drawing.     Added Typical Recommended Land Pattern. Removed package option Updated POD M8.15 to latest revision changes are as follow:     Changed Note 1 "1982" to "1994"     Changed in Typical Recommended Land Pattern the following:     2.41(0.095) to 2.20(0.087)     0.76 (0.030) to 0.60(0.023)     0.200 to 5.20(0.205)     Updated to new POD format by removing table and moving dimensions onto drawing and adding land pattern.
1.00	Jul.6.09	Added reliability information on page 1 under Features and EEPROM Specifications in DC Electrical Spec Table.
0.00	Mar.24.08	Initial release

## 7. Package Outline Drawings

For the most recent package outline drawing, see <u>L10.2.1x1.6A</u>.

L10.2.1x1.6A 10 Lead Ultra Thin Quad Flat No-Lead Plastic Package Rev 5, 3/10



#### NOTES:

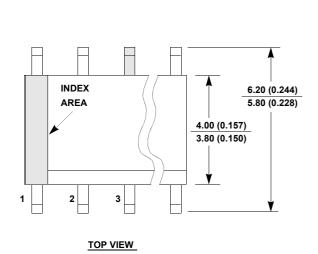
- 1. Dimensioning and tolerancing conform to ASME Y14.5M-1994.
- 2. All Dimensions are in millimeters. Angles are in degrees. Dimensions in ( ) for Reference Only.
- 3. Unless otherwise specified, tolerance : Decimal  $\pm 0.05$

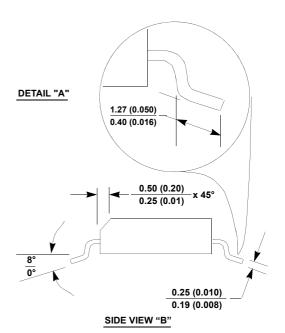
4. Lead width dimension applies to the metallized terminal and is measured between 0.15mm and 0.30mm from the terminal tip.

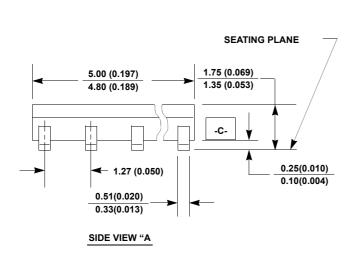
- 5. Maximum package warpage is 0.05mm.
- 6. Maximum allowable burrs is 0.076mm in all directions.
- Same as JEDEC MO-255UABD except: No lead-pull-back, MIN. Package thickness = 0.45 not 0.50mm Lead Length dim. = 0.45mm max. not 0.42mm.
- 8. The configuration of the pin #1 identifier is optional, but must be located within the zone indicated. The pin #1 identifier may be either a mold or mark feature.

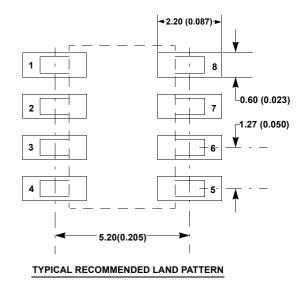
M8.15 8 Lead Narrow Body Small Outline Plastic Package Rev 4, 1/12

For the most recent package outline drawing, see <u>M8.15</u>.









#### NOTES:

- 21. Dimensioning and tolerancing per ANSI Y14.5M-1994.
- Package length does not include mold flash, protrusions or gate burrs.
   Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
- 23. Package width does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
- 24. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
- 25. Terminal numbers are shown for reference only.
- 26. The lead width as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch).
- Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.
- 28. This outline conforms to JEDEC publication MS-012-AA ISSUE C.

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## Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan

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